# Vishay Semiconductors

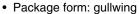


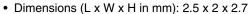
# Silicon NPN Phototransistor, RoHS Compliant



### **FEATURES**

· Package type: surface mount





- · High photo sensitivity
- High radiant sensitivity
- · Suitable for visible and near infrared radiation



- Angle of half sensitivity:  $\varphi = \pm 15^{\circ}$
- Floor life: 168 h, MSL 3, acc. J-STD-020
- Lead (Pb)-free reflow soldering
- Lead (Pb)-free component in accordance with RoHS 2002/95/EC and WEEE 2002/96/EC

#### **APPLICATIONS**

- · Detector in electronic control and drive circuits
- · Detector for light measurement

sensitivity in a clear, surface mount plastic package with	•
lens. It is sensitive to visible and near infrared radiation.	

TEMT1520 is a silicon NPN phototransistor with high radiant

PRODUCT SUMMARY			
COMPONENT	I <sub>ca</sub> (mA)	φ (deg)	λ <sub>0.1</sub> (nm)
TEMT1520	4.5	± 15	450 to 1080

#### Note

**DESCRIPTION** 

Test conditions see table "Basic Characteristics"

ORDERING INFORMATION			
ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM
TEMT1520	Tape and reel	MOQ: 1000 pcs, 1000 pcs/reel	Gullwing

#### Note

MOQ: minimum order quantity

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
Emitter collector voltage		V <sub>ECO</sub>	5	V	
Collector current		I <sub>C</sub>	50	mA	
Collector peak current	$t_p/T = 0.5, t_p \le 10 \text{ ms}$	I <sub>CM</sub>	100	mA	
Power dissipation	T <sub>amb</sub> ≤ 55 °C	$P_V$	100	mW	
Junction temperature		Tj	100	°C	
Operating temperature range		T <sub>amb</sub>	- 40 to + 85	°C	
Storage temperature range		T <sub>stg</sub>	- 40 to + 100	°C	
Soldering temperature	Acc. reflow solder profile fig. 8	T <sub>sd</sub>	< 260	°C	
Thermal resistance junction/ambient	Soldered on PCB with pad dimensions: 4 mm x 4 mm	R <sub>thJA</sub>	400	K/W	

#### Note

T<sub>amb</sub> = 25 °C, unless otherwise specified





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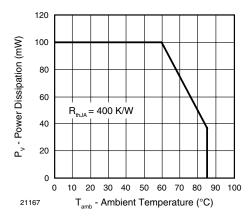


Fig. 1 - Power Dissipation Limit vs. Ambient Temperature

BASIC CHARACTERISTICS						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Collector emitter voltage	I <sub>C</sub> = 1 mA	$V_{CEO}$	70			V
Collector emitter dark current	V <sub>CE</sub> = 20 V, E = 0	I <sub>CEO</sub>		1	200	nA
Collector emitter capacitance	V <sub>CE</sub> = 5 V, f = 1 MHz, E = 0	C <sub>CEO</sub>		3		pF
Collector light current	$E_e = 1 \text{ mW/cm}^2, \lambda = 950 \text{ nm},$ $V_{CE} = 5 \text{ V}$	I <sub>ca</sub>	2	4.5	8	mA
Angle of half sensitivity		φ		± 15		deg
Wavelength of peak sensitivity		$\lambda_{p}$		850		nm
Range of spectral bandwidth		λ <sub>0.1</sub>		450 to 1080		nm
Collector emitter saturation voltage	$E_{e} = 1 \text{ mW/cm}^{2}, \lambda = 950 \text{ nm},$ $I_{C} = 0.1 \text{ mA}$	V <sub>CEsat</sub>			0.3	٧
Turn-on time	$V_S = 5 \text{ V}, I_C = 5 \text{ mA}, R_L = 100 \Omega$	t <sub>on</sub>		2.0		μs
Turn-off time	$V_S = 5 \text{ V}, I_C = 5 \text{ mA}, R_L = 100 \Omega$	t <sub>off</sub>		2.3		μs
Cut-off frequency	$V_S = 5 \text{ V}, I_C = 5 \text{ mA}, R_L = 100 \Omega$	f <sub>c</sub>		180		kHz

### Note

 $T_{amb}$  = 25 °C, unless otherwise specified

### **BASIC CHARACTERISTICS**

T<sub>amb</sub> = 25 °C, unless otherwise specified

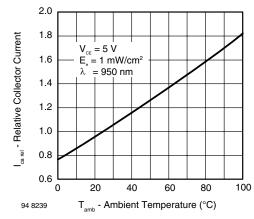


Fig. 2 - Relative Collector Current vs. Ambient Temperature

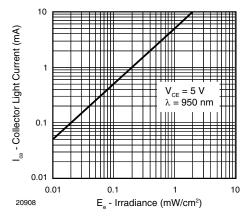


Fig. 3 - Collector Light Current vs. Irradiance

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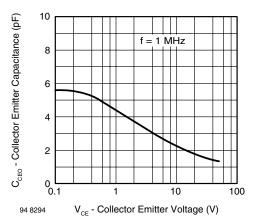


Fig. 4 - Collector Emitter Capacitance vs. Collector Emitter Voltage

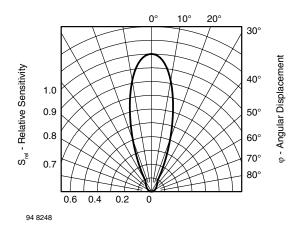


Fig. 7 - Relative Radiant Sensitivity vs. Angular Displacement

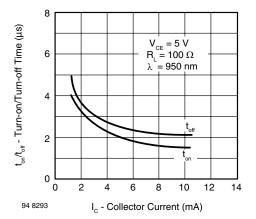


Fig. 5 - Turn-on/Turn-off Time vs. Collector Current

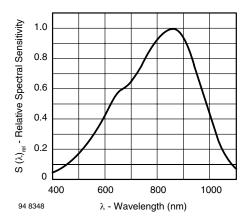


Fig. 6 - Relative Spectral Sensitivity vs. Wavelength

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### **PRECAUTIONS FOR USE**

### 1. Over-current-proof

Customer must apply resistors for protection, otherwise slight voltage shift will cause big current change (burn out will happen).

### 2. Storage

- 2.1 Storage temperature and rel. humidity conditions are: 5 °C to 35 °C, R.H. 60 %.
- 2.2 Floor life must not exceed 168 h, acc. to JEDEC level 3, J-STD-020.
  - Once the package is opened, the products should be used within a week. Otherwise, they should be kept in a damp proof box with desiccant.
  - Considering tape life, we suggest to use products within one year from production date.
- 2.3 If opened more than one week in an atmosphere 5 °C to 35 °C, R.H. 60 %, devices should be treated at 60 °C  $\pm$  5 °C for 15 h.
- 2.4 If humidity indicator in the package shows pink color (normal blue), then devices should be treated with the same conditions as 2.3.

#### **REFLOW SOLDER PROFILE**

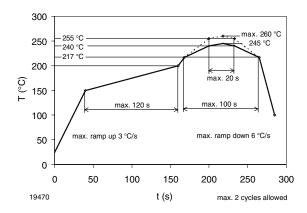
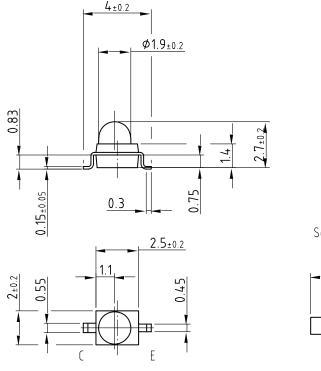


Fig. 8 - Lead (Pb)-free Reflow Solder Profile acc. J-STD-020D

## **PACKAGE DIMENSIONS** in millimeters



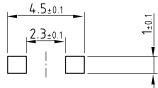
Drawing-No.: 6.544-5325.01-4

Issue: 5; 19.01.06

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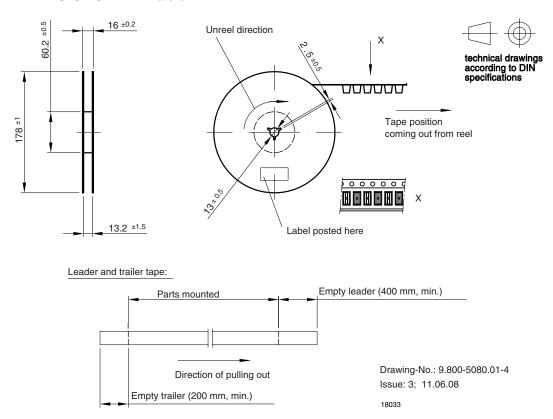
Solder pad proposal



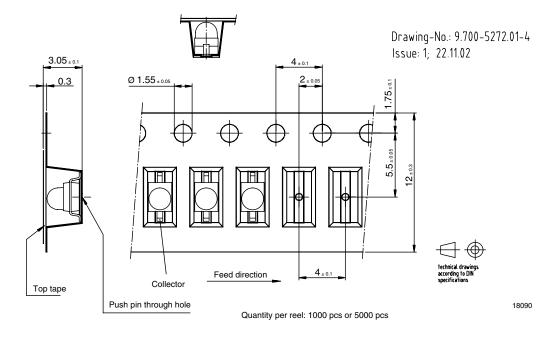
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## **REEL DIMENSIONS** in millimeters



## **TAPING DIMENSIONS** in millimeters





Vishay

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